

## SCHOTTKY BARRIER RECTIFIERS

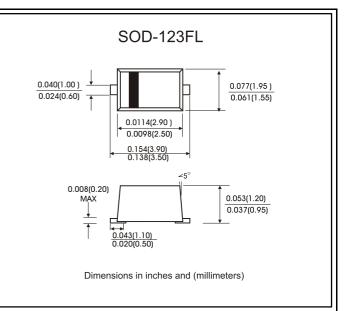
#### FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- $\cdot\,$  Metal silicon junction ,majority carrier conduction
- $\cdot\,$  Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,Low forward voltage drop
- High surge capability
- For use in low voltage ,high frequency inverters, free wheeling ,and polarity protection applications
- High temperature soldering guaranteed:250 C/10 seconds at terminals, 0.375"(9.5mm)lead length,5lbs.(2.3kg)tension

#### **MECHANICAL DATA**

- · Case: SOD-123FL molded plastic body
- Lead Finish: 100% Matte Sn (Tin)
- · Polarity: color band denotes cathode end
- Mounting Position: Any
- · Weight: 11.7 mg(approximately)

### VOLTAGE RANGE: 20 --- 200 V CURRENT: 1.0 A



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

	Symbols	K12	K13	K14	K15	K16	K18	K1A	K1B	K1D	Volts
Maximum repetitive peak reverse voltage	Vrrm	20	30	40	50	60	80	100	150	200	Volts
Maximum RMS voltage	Vrms	14	21	28	35	42	57	71	105	140	Volts
Maximum DC blocking voltage	Vdc	20	30	40	50	60	80	100	150	200	Volts
Maximum average forward rectified current (See Fig. 1)	I(A∨)	1.0								Amp	
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	Ifsm	40.0									Amps
Maximum instantaneous forward voltage at1.0 A(note 1 )	Vf	0.55			C	0.75 0		.85	0.90	0.95	Volts
$\begin{array}{c} \text{Maximum instantaneous reverse} \\ \text{current at rated DC blocking} \\ \text{voltage(Note 1)} \\ \end{array} \\ \begin{array}{c} T_{\text{A}} = 25^{\circ}\text{C} \\ T_{\text{A}} = 100^{\circ}\text{C} \end{array}$	IR	0.2									mA
Typical thermal resistance (Note 2)	R₀ ja R₀ jl	88.0 28.0									°C/W
Operating junction temperature range	ΓJ	-65 to+150								°C	
Storage temperature range	Tstg	-65 to+150									°C

NOTE: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

2. Thermal resistance from junction to ambient.

# **RATINGS AND CHARACTERISTIC CURVES**

# K12 --- K1D

